

BT137

双向可控硅
TRIAC版本号
201603-A

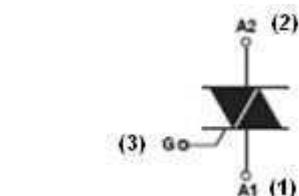
产品概述 GENERAL DESCRIPTION

BT137 双向可控硅采用穿通隔离台面结构，复合玻璃钝化PN结表面保护工艺技术， dv/dt 高，可靠性高，适用于控温、调光、马达控制。

BT137 Triacs is fabricated using separation diffusion processes ,the junction termination areas are passivated with glass. Thanks to highly dv/dt and reliability,the Triacs series is suitable for domestic lighting ,heating and motor speed controllers.

主要参数 MAIN CHARACTERISTICS

参数 Parameter	数值 Value	单位 Unit
$I_T(RMS)$	8	A
V_{DRM}/V_{RRM}	600	V
$I_{GT(HI)}$	≤ 10	mA



TO-220AB

产品特性 FEATURES

- dv/dt 高
- 通态压降低
- RoHS环保产品
- Highly dv/dt
- Low on-state voltage
- RoHS Products

应用领域 APPLICATIONS

主要应用于调光、控温、马达控制。

domestic lighting ,heating and motor speed controllers.

极限值(除非另有规定, $T_j=25^\circ\text{C}$) ABSOLUTE RATINGS

($T_j=25^\circ\text{C}$,unless otherwise specified)

符号 Symbol	参数 Parameter	数值 Value	单位 Unit
$I_{T(\text{RMS})}$	RMS 通态电流 RMS on-state current (full sine wave)	8	A
I_{TSM}	通态峰值浪涌电流 Non repetitive surge peak on-state current	65	A
I^2t	I^2t 耗散值 I^2t value for fusino	21	A^2s
di/dt	通态电流上升值 Critical rate of rise of on-state current	50	$\text{A}/\mu\text{s}$
I_{GM}	门极峰值电流 Peak gate current	2	A
$P_{G(\text{AV})}$	平均门极耗散功率 Average gate power dissipation	0.5	W
T_{stg}	贮存结温范围 Storage junction temperature range	-40~+150	$^\circ\text{C}$
T_j	工作结温范围 Operating junction temperature range	-40~+125	$^\circ\text{C}$

电参数(除非另有规定, $T_j=25^\circ\text{C}$) ELECTRICAL CHARACTERISTICS

($T_j=25^\circ\text{C}$,unless otherwise specified)

参数 Parameter	符号 Symbol	规范值 Value		单位 Unit	测试条件 Test Conditions
		D	E		
触发电流 Gate trigger current	I_{GT}	$I \sim III$ ≤ 5	≤ 10	mA	$V_D=12\text{V}, I_T=0.1\text{A}$
		IV ≤ 10	≤ 25		
触发电压 Gate trigger voltage	V_{GT}	I ~ IV	≤ 1.5		V $V_D=12\text{V}, I_T=0.1\text{A}$
维持电流 Holding current		I_H	≤ 20	≤ 30	mA $V_D=12\text{V}, I_T=0.1\text{A}$
擎住电流 Latching current		I_L	≤ 30	≤ 35	mA $V_D=12\text{V}, I_T=0.1\text{A}$
电压上升率 Rise of off- state voltage		dv/dt	≥ 20	≥ 50	V/ μs $V_D=67\%V_{DRM}$
通态压降 Peak on-state voltage		V_{TM}	≤ 1.65		V $I_T=10\text{A}$
断态漏电流 Peak repetitive forward blocking current	I_{DRM}	≤ 10		μA	$V_{RRM}=V_{DRM}, T_j = 25^\circ\text{C}$
		≤ 0.5		mA	$V_{RRM}=V_{DRM}, T_j = 125^\circ\text{C}$

热特性 THERMAL RESISTANCES

符号 Symbol	参数 Parameter	数值 Value	单位 Unit
$R_{th(j-c)}$	Junction to case(AC)	1.8	$^\circ\text{C}/\text{W}$
$R_{th(j-a)}$	Junction to ambient	60	$^\circ\text{C}/\text{W}$

特征曲线 ELECTRICAL CHARACTERISTICS (CURVES)

图1 最大耗散功率与RMS通态电流关系
Fig.1. Maximum Power Dissipation Versus
on-state current

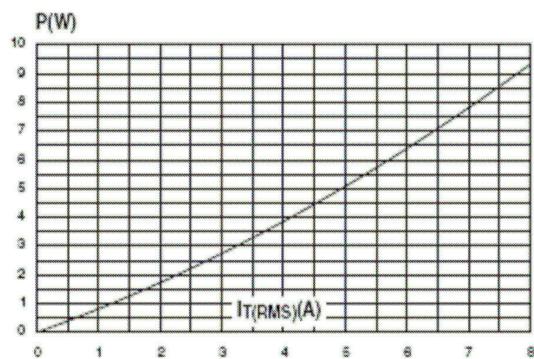


图3 通态特性
Fig.3.On-State Characteristics

图2 RMS通态电流与Tc温度关系
Fig.2. RMS On-state Current Versus TL
on-state current

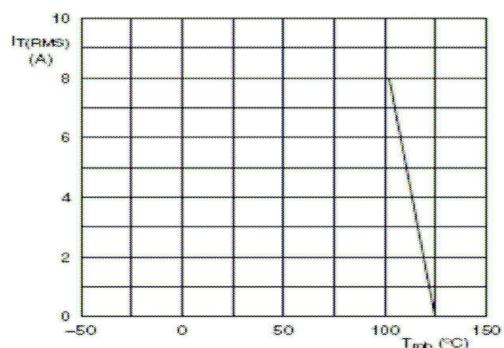


图4 通态浪涌峰值电流与周期数关系
Fig.4.Surge Peak On-state Current Versus Number Cycles

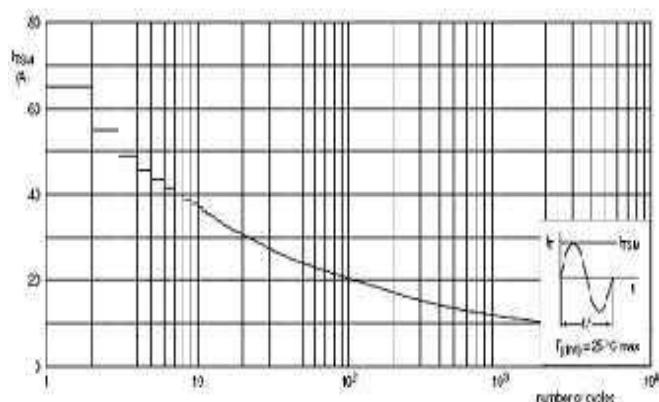
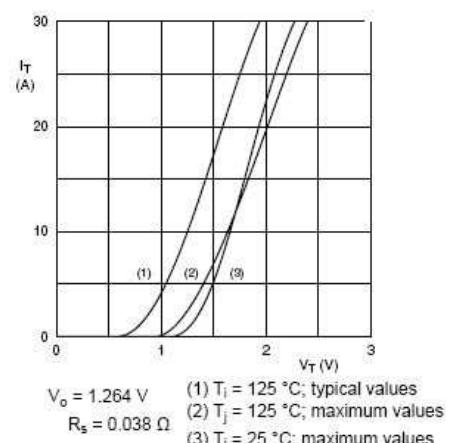
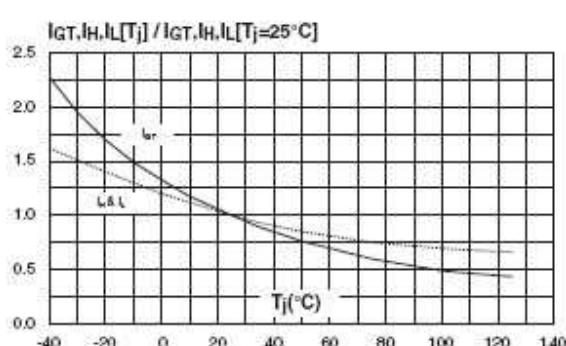


图5 IGT、IH、IL相对值（相对于25℃）与结温关系
Fig.5.Relative Variation Of Gate Trigger Current
, Holding Current And Latching Current Versus Junction Temperature (Typical Value)



封装尺寸 PACKAGE MECHANICAL DATA

TO-220AB

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.70	0.244		0.264
Ø1	3.70		3.85	0.146		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

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